Composite Transistors

Panason

XP0121L

Silicon NPN epitaxial planar type

For digital circuits

Features

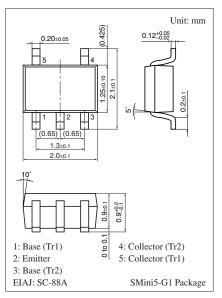
- · Two elements incorporated into one package (Transistors with built-in resistor)
- Reduction of the mounting area and assembly cost by one half

Basic Part Number

• UNR121L \times 2

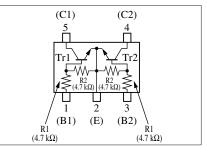
Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V _{CBO}	50	V
Collector-emitter voltage (Base open)	V _{CEO}	50	V
Collector current	I _C	100	mA
Total power dissipation	P _T	150	mW
Junction temperature	Tj	150	°C
Storage temperature	T _{stg}	-55 to +150	°C



Marking Symbol: DB

Internal Connection



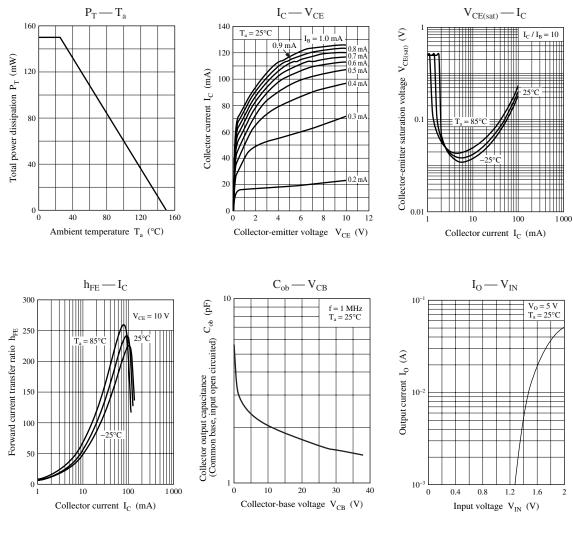
Parameter Symbol Conditions Max Unit Min Тур v Collector-base voltage (Emitter open) $I_{C} = 10 \ \mu A, I_{E} = 0$ 50 V_{CBO} Collector-emitter voltage (Base open) $I_{C} = 2 \text{ mA}, I_{B} = 0$ 50 V V_{CEO} Collector-base cutoff current (Emitter open) $V_{CB} = 50 \text{ V}, I_E = 0$ I_{CBO} 0.1 μΑ $V_{CE} = 50 \text{ V}, I_B = 0$ Collector-emitter cutoff current (Base open) I_{CEO} 0.5 μΑ $V_{EB} = 6 V, I_C = 0$ Emitter-base cutoff current (Collector open) 2.0 $I_{\rm EBO}$ mA $V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$ Forward current transfer ratio h_{FE} 20 $V_{CE} = 10 \text{ V}, I_C = 5 \text{ mA}$ 0.5 h_{FE} Ratio h_{FE(Small} 0.99 /Large) $I_{C} = 10 \text{ mA}, I_{B} = 0.3 \text{ mA}$ 0.25 V Collector-emitter saturation voltage V_{CE(sat)} Output voltage high-level V_{OH} $V_{CC} = 5 \text{ V}, V_B = 0.5 \text{ V}, R_L = 1 \text{ k}\Omega$ 4.9 V $V_{CC} = 5 V, V_B = 2.5 V, R_L = 1 k\Omega$ Output voltage low-level VOL 0.2 v 4.7 +30% Input resistance R_1 -30% kΩ Resistance ratio 0.8 1.0 1.2 R_1 / R_2 Transition frequency \mathbf{f}_{T} $V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$ 150 MHz

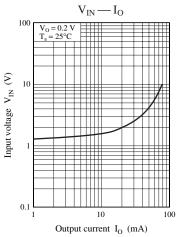
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors. 2. *: Ratio between 2 elements

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

XP0121L







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